





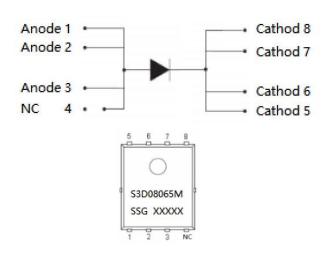
S3D08065M 650V SIC POWER SCHOTTKY RECTIFIER



Description

S3D08065M is a SiC Schottky rectifier packaged in PDFNWB5×6-8L case. The device is a high voltage Schottky rectifier that has very low total conduction losses and very stable switching characteristics over temperature extremes. The S3D08065M is ideal for energy sensitive, high frequency applications in challenging environments.

Circuit Diagram



Features

- 175°C T_J operation
- Ultra-low switching loss
- Switching speeds independent of operating temperature
- Low total conduction losses
- High forward surge current capability
- High package isolation voltage
- Terminals finish: 100% Pure Tin
- Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request

Applications

- Alternative energy inverters
- Power Factor Correction (PFC)
- Free-Wheeling diodes
- Switching supply output rectification
- Reverse polarity protection







Maximum Ratings

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{DC}	-	650	V
Average Rectified Forward Current	I _{F (AV)1}	@Tc=25°C	24	Α
, wording the same at a small a current	I _{F (AV)2}	@Tc=153°C	8	А
Repetitive Peak Forward Surge Current	I _{FRM1}	10ms, Half Sine pulse, T _C =25°C	37.5	Α
Repetitive Feak Forward Surge Current	I _{FRM2}	10ms, Half Sine pulse, T _C =110°C	25.5	Α
Book One Cycle New Bonetitive Cymre Cymret	I _{FSM1}	10ms, Half Sine pulse, T _C =25°C	71	Α
Peak One Cycle Non-Repetitive Surge Current	I _{FSM2}	10ms, Half Sine pulse, T _C =110°C	60	Α
Non-Repetitive Peak Forward Surge Current	I _{F,Max1}	10µs. Pulse, T _C =25℃	650	Α
Non-repetitive reak rotward Surge Current	I _{F,Max2}	10µs. Pulse, T _C =110°C	530	Α
Dower Discinction	P _{tot1}	T _J =25℃	79.0	W
Power Dissipation	P _{tot2}	T _J =110°C	34.2	W

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1} @ 8A, Pulse, T _J = 25 °C		1.4	1.7	V
	V_{F2}	@ 8A, Pulse, T _J = 175 °C	1.7	2.4	V
Reverse Current*	I _{R1}	$@V_R = \text{rated } V_R$ $T_J = 25 ^{\circ}\text{C}$	3	20	uA
	I _{R2}	$@V_R = \text{rated } V_R$ $T_J = 175 ^{\circ}\text{C}$	30	200	uA
Junction Capacitance	Ст	VR=0V, Tj=25℃,f=1MHz	650	-	pF
Reverse Recovery Charge	Qc	I_F = 8A, di/dt = 500A/ μ s VR = 400 V, T $_J$ =25°C	40.55	-	nC
Capacitance Stored Energy	E c	V _R = 400 V	9.93	-	μJ

^{*} Pulse width < 300 μ s, duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +175	°C
Storage Temperature	T _{stg}	-	-55 to +175	°C
Typical Thermal Resistance Junction to Case	R _θ JC	DC operation	1.9	°C/W

- China Germany Korea Singapore United States
 - http://www.smc-diodes.com sales@ smc-diodes.com •







Marking Diagram



Where XXXXX is YYWWL

S3D = Device Type = Package type = Forward Current (8A) 80 065 = Reverse Voltage (650V) SSG = SSG = Year ww = Week = Lot Number

Cautions: Molding resin

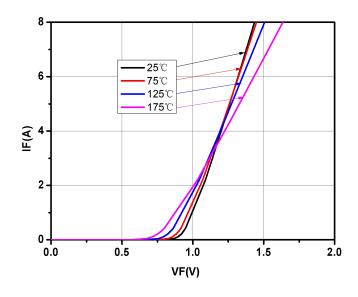
Epoxy resin UL:94V-0

Ordering Information

Device	Package	Shipping
S3D08065M	PDFNWB5×6-8L	3000pcs/Reel
S3D08065MTR	PDFNWB5×6-8L	3000pcs/Reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Ratings and Characteristics Curves



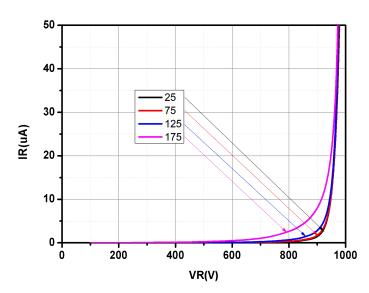


Fig.1-Typical Forward Voltage Characteristics

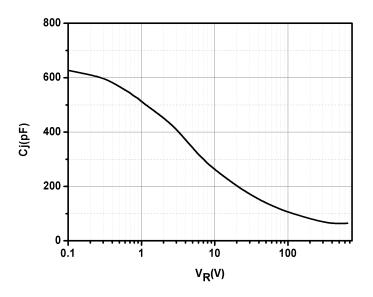
Fig.2-Typical Reverse Characteristics

- China Germany Korea Singapore United States
 - http://www.smc-diodes.com sales@ smc-diodes.com •









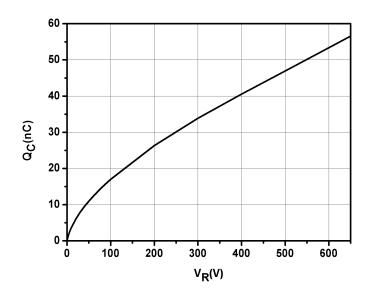
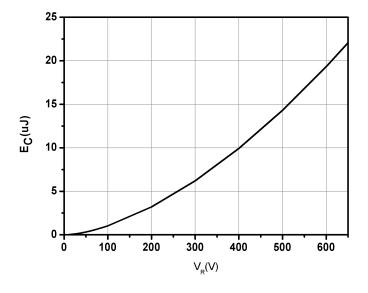


Fig.3-Capacitance vs. Reverse Voltage

Fig.4-Total Capacitance Charge vs. Reverse Voltage



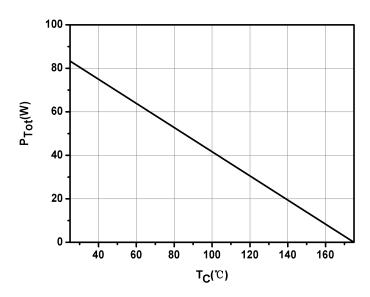


Fig.5-Capacitance Stored Energy

Fig.6-Power Derating

- China Germany Korea Singapore United States
 - http://www.smc-diodes.com sales@ smc-diodes.com •







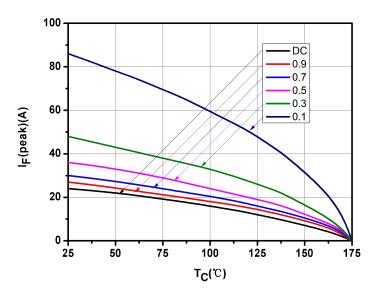
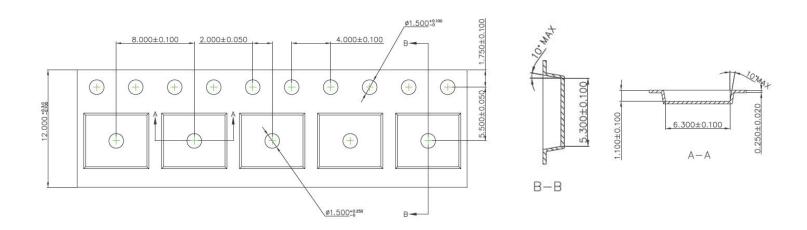


Fig.7-Current Derating

Carrier Tape & Reel Specification PDFNWB5×6-8L



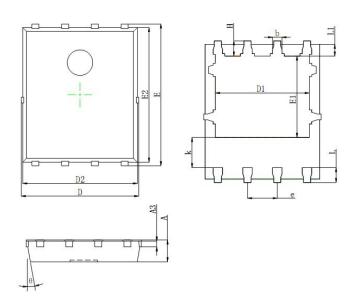
[•] http://www.smc-diodes.com - sales@ smc-diodes.com •







Mechanical Dimensions PDFNWB5×6-8L



SYMBOL	Millin	neters	Inches		
STWIBOL	Min.	Max.	Min.	Max.	
Α	0.900	1.000	0.035	0.039	
A3	0.254 REF.		0.010REF.		
D	4.944	5.096	0.195	0.201	
E	5.974	6.126	0.235	0.241	
D1	3.910	4.110	0.154	0.162	
E1	3.375	3.575	0.133	0.141	
D2	4.824	4.976	0.190	0.196	
E2	5.674	5.826	0.223	0.229	
k	1.190	1.390	0.047	0.055	
b	0.350	0.450	0.014	0.018	
е	1.270	TYP.	0.050 TYP.		
L	0.559	0.711	0.022	0.028	
L1	0.424	0.576	0.017	0.023	
Н	0.574	0.726	0.023	0.029	
Θ	10°	12°	10°	12°	

DISCLAIMER:

- 1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the SMC Diode Solutions sales department for the latest version of the datasheet(s).
- 2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.
- 3- In no event shall SMC Diode Solutions be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). SMC Diode Solution assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.
- 4- In no event shall SMC Diode Solutions be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.
- 5- No license is granted by the datasheet(s) under any patents or other rights of any third party or SMC Diode Solutions.
- 6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of SMC Diode Solutions
- 7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations.
 - China Germany Korea Singapore United States
 - http://www.smc-diodes.com sales@ smc-diodes.com •